

NPN Darlington Transistor MPSA29

Description

This device is designed for applications requiring extremely high current gain at collector currents to 500 mA. Sourced from process 03. See MPSA28 for characteristics.

Features

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS (Notes 1, 2)

(Values are at $T_A = 25^{\circ}$ C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	100	V
Collector-Base Voltage	V_{CBO}	100	V
Emitter-Base Voltage	V _{EBO}	12	V
Collector Current – Continuous	I _C	800	mA
Operating and Storage Junction Temperature Range	T _J , T _{STG}	-55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

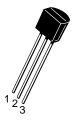
- 1. These ratings are based on a maximum junction temperature of 150 $^{\circ}$ C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

THERMAL CHARACTERISTICS (Note 3)

(Values are at T_A = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Total Device Dissipation	P_{D}	625	mW
Dissipation Derate Above 25°C	P_{D}	5.0	mW/°C
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	83.3	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	200	°C/W

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



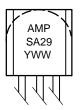
TO-92-3 CASE 135AN Straight Lead Bulk Packing



TO-92-3 CASE 135AR Bent Lead Tape & Reel Ammo Packing

- 1. Emitter
- 2. Base
- 3. Collector

MARKING DIAGRAM



A = Assembly Code MPSA29 = Device Code YWW = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

MPSA29

ELECTRICAL CHARACTERISTICS (Note 4)

(Values are at T_A = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Max.	Unit
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 100 μA, I _B = 0	100		V
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 100 μA, I _E = 0	100		V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	12		V
I _{CBO}	Collector Cut-Off Current	V _{CB} = 80 V, I _E = 0		100	nA
I _{CES}	Collector Cut-Off Current	$V_{CE} = 80 \text{ V}, I_{E} = 0$		500	nA
I _{EBO}	Emitter Cut-Off Current	V _{EB} = 10 V, I _C = 0		100	nA
h _{FE}	DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$	10,000		
		$V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$	10,000		
V _{CE} (sat)	Collector–Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 0.01 \text{ mA}$		1.2	V
		$I_C = 100 \text{ mA}, I_B = 0.1 \text{ mA}$		1.5	V
V _{BE} (on)	Base-Emitter On Voltage	$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$		2.0	V
f _T	Current Gain – Bandwidth Product	$I_C = 15 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz}$	125		MHz
C _{obo}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1.0 MHz		8.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

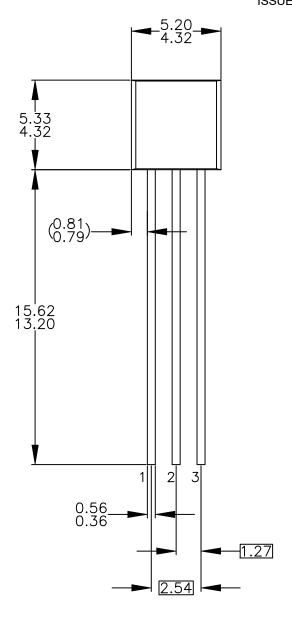
Part Number	Top Mark	Package	Shipping [†]
MPSA29	MPSA29	TO-92-3, case 135AN (Pb-Free)	10,000 Units/ Bulk Box
MPSA29-D26Z	MPSA29	TO-92-3, case 135AR (Pb-Free)	2,000 Units/ Tape & Reel

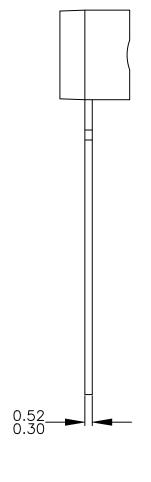
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{4.} Pulse test: pulse width ≤ 300 μs, duty cycle ≤ 2.0%

TO-92 3 4.825x4.76 CASE 135AN ISSUE O

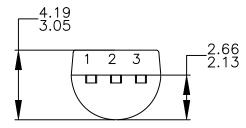
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NOTES: UNLESS OTHERWISE SPECIFIED

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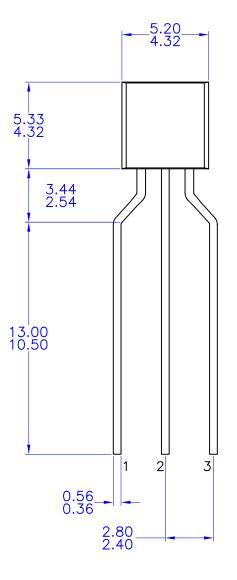
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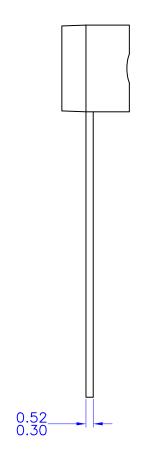
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TO-92 3 4.83x4.76 LEADFORMED

CASE 135AR ISSUE O

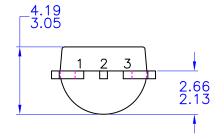
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